

No. 20B-3 SbSI–AsSI

| | | |
|-----|--|-------|
| 1b | As _{0.1} Sb _{0.9} SI shows a ferroelectric transition: $\Theta_f = 0$ °C. | 64Nit |
| 2a | Partial replacement of Sb by As in SbSI is possible under conservation of the SbSI structure, although the isostructural pure compound AsSI is not known to exist. | 64Nit |
| 5a | Dielectric constants: ϵ_p , ϵ_f and C: Table 20B-3-001. Dielectric constants in optical region: see 9a | |
| 9a | Dielectric constants obtained from reflectivity: Fig. 20B-3-001. | |
| 10a | Raman scattering: Fig. 20B-3-002. See also | 80Par |